

SYNOPSIS OF

**“Structure, Microstructure, Transport, Magnetic and Dielectric studies of some  $ABO_2$  type compounds in Bulk form”**

A THESIS

*To be submitted by*

**Barot Nishant Jayeshkumar**

*For the award of the degree of*

**DOCTOR OF PHILOSOPHY**

**IN**

**PHYSICS**

**UNDER THE GUIDANCE OF**

**Dr. Prashant K. Mehta**

DEPARTMENT OF PHYSICS

FACULTY OF SCIENCE

THE MAHARAJA SAYAJIRAO UNIVERSITY OF BARODA,

VADODARA-390002, GUJARAT INDIA

July 2021

## **Introduction:**

General formula of delafossite is  $A^{+1}B^{+3}O_2^{2-}$  ( $ABO_2$ ) and are extensively studied due to their potential applications of catalysis [1-3], ozone sensors [4], diluted magnetic semiconductors [5], light emitting diodes [6], and transparent conducting oxides (TCO) [7]. Also they are known to exhibit both multiferroic and Spintronic properties [8]. The findings of H. Hosono and his co-workers on copper (I) – based transparent oxides is an important contribution towards this development [9-12]. These systems are promising candidates to fulfill the technical application demands and mass production. The processing for this has to be flexible and low cost.

The mineral compound  $CuFeO_2$  was first noted by Friedel in 1873 during the analysis of a sample from Siberia [13] and was named Delafossite in honor of the French mineralogist and crystallographer Gabriel Delafosse. The existence of the same was confirmed by Roger in most of the copper mines in America [14, 15]. Delafossite structure was first established by Soller and Thompson through synthetically prepared sample [16].

The delafossite oxides have general formula  $ABO_2$ , which is characterized by linear coordination of the monovalent  $A^{+}$  cations by  $O^{2-}$  anions and octahedral coordination of the trivalent  $B^{3+}$  cations by  $O^{2-}$  anions. Together with the complementary pseudo-tetrahedral coordination of the  $O^{2-}$  ions by three  $B^{3+}$  ions and one  $A^{+}$  ion results in two distinct structural units: Edge-sharing  $MO_6$  octahedral, forming a flat layer, and parallel oriented O-Cu-O dumbbells linking them, resulting in a triangular pattern of  $A^{+}$  ions [16].

$CuFeO_2$  exhibits both multiferroic and Spintronic properties [8]. Substitutional effects on the Fe site of  $CuFeO_2$  have been studied by various research groups. Nozaki et al.[17] showed that the substitution of Ni with less than 2% at Fe sites results in an enhanced electrical conductivity of  $CuFeO_2$ . On the other hand, doping of 5% Mn at the Fe sites was

found to decrease the thermal conductivity [18]. Hayashi et al. [19] observed no distinct change in the structural parameters, on contrast, a decrease in antiferromagnetic (AF) phase transition temperature is seen with Mn doping.  $\text{CuFeO}_2$  can be made p-type or n-type semiconductor with Mg and Sn doping, respectively. The mobility is much higher in p-type samples [20]. Ferro-electricity was observed by Singh et al. [21] on doping 50% V at Fe sites that exhibited the features of the glass-like relaxor state. Mössbauer studies found that doping of V at Fe sites affects magnetic behavior, which changes from 2D ferrimagnetic-like one to a 3D antiferromagnetic one with a Néel temperature greater than 4.5 K [22]. Shi et al. [23] observed on doping of  $\text{Ga}^{3+}$  at Fe sites an expansion of ferroelectric in commensurate state was induced. Elkhouni et al. [24] observed  $\text{Ca}^{+2}$  doping at the Fe site caused suppression of magnetic properties, while it boosted in the case of  $\text{Mg}^{2+}$  doping. Seki et al. [25] showed a significant change in the magnetic phase diagram with Al doping at Fe sites, where ferroelectricity became apparent with Al doping up to 2%. These results show that the electronic and magnetic properties of these systems are significantly dependent on the interplay of the microstructure modifications carried out by doping of different ions. In addition to the above mentioned observations, Dordor et al.[26] prepared polycrystalline and single crystals of  $\text{CuFeO}_2$ , which were found to be of n-type with a very low conductivity [ $1.9 \times 10^{-5} \Omega^{-1} \text{cm}^{-1}$  for polycrystalline and for single crystal  $6.5 \times 10^{-7} \Omega^{-1} \text{cm}^{-1}$  ( $\parallel$ ) and  $3.1 \times 10^{-4} \Omega^{-1} \text{cm}^{-1}$  ( $\perp$ )].

Another interesting and identical delafossite system is  $\text{CuCrO}_2$ , having the same structure but possessing the alternating stacking of layered structure with edge shared  $\text{CrO}_6$  octahedra and Cu layers, resulting in antiferromagnetic triangular sublattice [27].  $\text{CuCrO}_2$  exhibits a bandgap of 3.1 eV with p-type nature as revealed by the Seeback measurements, while the mobility of charge carriers is too low for the Hall Effect measurement [28]. Beneath its Neel temperature ( $T_N = 25$  K),  $\text{CuCrO}_2$  exhibits both antiferromagnetic [29] and

ferroelectric [30] nature. It has been observed that reported studies mainly focused on the effects of doping on the structural, electrical and magnetic properties in the  $\text{CuCrO}_2$  system, but with no consistency on percentage of doping.  $\text{Mg}^{2+}$  substitutions at the Cr site drastically decrease the resistivity without changing the Neel temperature [27]. The doping of Ni at Cr site also increases the conductivity of the  $\text{CuCrO}_2$  system [31]. A weak ferromagnetism is induced and destabilization of antiferromagnetic ordering of  $\text{Cr}^{3+}$  occurs due to doping of  $\text{Al}^{3+}$  ions [32]. Sc doping causes local lattice distortions thereby breaking of the residual magnetic degeneracy occurring in the  $\text{CuCrO}_2$  system [33]. Correlated variation of (Cr, Rh–O) bonds and shifting of Raman active modes was observed in  $\text{CuCr}_{1-x}\text{Rh}_x\text{O}_2$  [34]. The  $\text{CuCrO}_2$  compound exhibits spin induced ferroelectricity and polarization below the magnetic phase transition temperature  $T_N$  in the absence of a magnetic field [30, 35]. Ferroelectricity is induced in  $\text{CuCrO}_2$  when it becomes antiferromagnetic (below  $T_N = 24$  K) with non-collinear spin ordering [30, 36].

**Motivation:**

In the view of the above findings, it was realized that isolated dopings were carried out but no concrete efforts have been made to understand the effect of iso- and polyvalent substitutions on short and long range crystalline order and how observed changes in order may affect transport and magnetic properties in these technologically important systems. It is therefore desirable to establish better correlation between long-range structural changes and local distortions with various isovalent and non-isovalent dopants. This requires the careful selection of dopants based on the ionic radius, coordination number, valence state to achieve p-type or n-type carrier and optimization of dopant concentration. The resultant effort is likely to provide a better understanding of the role of changes in ionic radii, valence and bond length of these systems having p-type and n-type dopings.

Therefore it motivated us to perform a detailed investigation with doping of iso- or poly-valent elements at the M site to shed light on the long and short-range crystalline order in  $\text{CuMO}_2$  type delafossites where  $M = \text{Fe}$  or  $\text{Cr}$ . We also desire to observe the effects of such a doping on the local polarizations/dipole moments and crystal structure leading to changes in the electronic structure related physical parameters, at room temperature as well as at low temperatures.

Moreover, the methods to prepare  $\text{CuFeO}_2$  through solid-state reaction also require inert atmosphere provided by gases like nitrogen, argon, etc., [18-25], which are expensive and hazardous. As an economical alternative we proposed to prepare pure and doped  $\text{CuFeO}_2$  compounds through a novel synthesis route involving a solid-state technique using high vacuum.

### **Objectives and scope:**

In the present study, the effects of local structure variations due to doping of iso- and poly-valent elements at the M site of  $\text{CuMO}_2$  ( $M = \text{Fe}/\text{Cr}$ ) are correlated to the micro- and macro-structural properties of compounds. This has been analyzed through the crystal structure, microstructure, optical studies, transport, magnetic and dielectric measurements.

Two delafossite systems were selected:

➤  $\text{CuFeO}_2$  system:

Samples of  $\text{CuFeO}_2$ ,  $\text{CuFe}_{0.96}\text{M}_{0.03}\text{V}_{0.01}\text{O}_2$  (where  $M = \text{Ti}$ ,  $\text{Ga}$ , and  $\text{Mn}$ ), and  $\text{CuFe}_{0.96}\text{V}_{0.04}\text{O}_2$  were prepared through novel synthesis route involving a solid-state technique using high vacuum.

➤ CuCrO<sub>2</sub> system:

Samples of CuCrO<sub>2</sub>, CuCr<sub>0.96</sub>M<sub>0.03</sub>V<sub>0.01</sub>O<sub>2</sub> (M = Ti, Mn, Ga, and Nb), CuCr<sub>0.96</sub>V<sub>0.04</sub>O<sub>2</sub>, CuCr<sub>0.97</sub>Mg<sub>0.03</sub>O<sub>2</sub>, CuCr<sub>0.97</sub>Ni<sub>0.03</sub>O<sub>2</sub> and CuCr<sub>1-x</sub>Fe<sub>x</sub>O<sub>2</sub> (x = 0.03, 0.06 and 0.09) were prepared by conventional solid-state technique.

- Majority of the samples are maintained with maximum doping level of 4%, as majority of the ions in these compounds has the same maximum substitutional limits [17, 23, 24].
- 1% V has been added to the compositions to limit the phase formation temperature. Such a reduction in the phase formation temperature has been reported earlier [37, 38].
- The considered ionic charge and ionic radii are based on the assumption that the dopant is expected to prefer the valence state whose radii is closest to the parent elements radii (Cr<sup>3+</sup> and Fe<sup>3+</sup>).
- In case of CuFeO<sub>2</sub> systems, room temperature Mossbauer spectroscopy is performed to confirm the spin state of Fe and can be correlated to Raman observations to provide a better insight into these compounds with respect to the role of defects/distortion in the physical properties.

Here attempts are made to explain the role of dopants on the long and short-range crystalline order in the above systems, through combined study of Raman and Fourier transformed Infrared spectroscopy (FTIR) along with long-range order dependent X-ray diffraction (XRD). Observed changes in the local polarizations/dipole moments and crystal structure can lead to changes in the electronic structure related physical parameters at room temperature as well as at low temperatures which were investigated using the optical measurements, electrical resistivity measurements, magnetization measurements, and dielectric measurements for these samples.

## **Proposed content of the thesis:**

The proposed thesis will comprise of the following chapters.

### **Chapter 1**

The introductory part of the thesis includes, in brief, the origin of the delafossite compounds and modification to parent compounds to be investigated will be introduced here. The mineral group delafossite is introduced in detail with its structure, properties and other features. The detailed literature survey on the previous work done on the mineral group delafossite and the observed results along with their explanation are presented. Further, the deficiencies in the work done and work needed to be done is highlighted in this chapter. Motivations to the research problem chosen, along with its objectives are clearly explained here.

### **Chapter 2**

In this chapter experimental laboratory work will be discussed. It starts with the sample preparation technique used for the preparation of the bulk samples. Broadly for the both  $\text{CuCrO}_2$  and  $\text{CuFeO}_2$  systems solid state reaction technique is used. This technique along with its details is described here. Sample preparation starts with the stoichiometric weighing, uniform mixing (wet mixing), calcination, sintering and finally annealing of the samples. This method requires high temperature muffle furnace with super kanthal (melting temp  $\sim 1200$  °C) as heating element. Particularly for  $\text{CuFeO}_2$  system a novel synthesis route involving a solid-state technique using high vacuum is used which is described here.

Characterization of the prepared samples was done under four different categories:

1. Structural characterization (Crystal structure and microstructural studies)
2. Optical and near optical measurements
3. Transport measurements

#### 4. Magnetic and dielectric measurements

Structural characterization is done using the X-ray diffraction (XRD) and scanning electron microscopy.

Optical studies include Uv-visible technique; Raman and Fourier transform Infrared spectroscopy (FTIR) study.

Transport measurements include d.c. conductivity measurements using the four probe technique and a.c. conductivity.

Magnetic characterization of the samples was carried out using the squid magnetometer (quantum design). Dielectric measurements were carried out by measuring the capacitance as a function of temperature.

### **Chapter 3**

In this chapter the analysis of the crystal structure and microstructure is presented. Details of the crystal structure and the identification of the crystallographic data are presented. The rietveld refinement technique through the Fullprof software [39] is used for the crystallographic studies. Crystallographic parameters like, space group, lattice parameters, Wyckoff position of each element, etc are determined for both  $\text{CuCrO}_2$  and  $\text{CuFeO}_2$  systems using the refined data. Scanning electron microscopy (SEM) is used to study the microstructures of the prepared samples.

### **Chapter 4**

In this chapter the optical and near optical studies are presented. The effect of doping on the local structure of the samples is studied in detail using the Raman and FTIR techniques. The combined results and analysis of the Raman and FTIR measurements are

presented in this chapter. Further the effects of the local structure variation on the electronic band gap were also studied using the Uv-Visible measurements. Correlations of these results, obtained from above measurements, are presented in this chapter.

## **Chapter 5**

The observed local distortions and changes in dipole moments due to above doping were observed through Raman and FTIR studies. This can also have potential effects on the transport properties. Therefore, in this chapter results of transport measurements are also been presented in the range of low temperature to room temperature using Four probe method. Suitable conduction model were fitted to explain the conduction mechanism. The same is correlated with the a.c. conductivities of the samples measured through dielectric measurements.

## **Chapter 6**

In this chapter the magnetic and dielectric studies of the samples are presented in detail. Magnetic studies are performed within the temperature range of 25 K to 300 K. Effect of the dopants on the magnetic behaviour of the samples has been discussed here. In order to probe the multiferroic behavior of the samples dielectric measurements were also been performed and analyzed in identical temperature range.

## **Chapter 7**

In this chapter all the major achievements and the conclusions of the work are compiled. At the end future scope of the above work is discussed.

## References:

- 1) S. Kato, R. Fujimaki, M. Ogasawara, T. Wakabayashi, Y. Nakahara, and S. Nakata, "Oxygen storage capacity of  $\text{CuMO}_2$  ( $M = \text{Al, Fe, Mn, Ga}$ ) with a delafossite-type structure," *Appl. Catal. B* 89, 183–188 (2009).
- 2) W. Ketir, A. Bouguelia, and M. Trari, " $\text{NO}_3^-$  removal with a new delafossite  $\text{CuCrO}_2$  photocatalys," *Desalination* 244, 144–152 (2009).
- 3) S. Bassaid, M. Chaib, S. Omeiri, A. Bouguelia, and M. Trari, "Photocatalytic reduction of cadmium over  $\text{CuFeO}_2$  synthesized by sol–gel," *J. Photochem. Photobiol. A* 201, 62–68 (2009).
- 4) S. Zhou, X. D. Fang, Z. H. Deng, D. Li, W. W. Dong, R. H. Tao, G. Meng, and T. Wang, "Room temperature ozone sensing properties of p-type  $\text{CuCrO}_2$  nanocrystals," *Sens. Actuators B* 143, 119–123 (2009).
- 5) D. Li, X. D. Fang, W. W. Dong, Z. H. Deng, R. H. Tao, S. Zhou, J. M. Wang, T. Wang, Y. P. Zhao, and X. B. Zhu, "Magnetic and electrical properties of p-type Mn-doped  $\text{CuCrO}_2$  semiconductors," *J. Phys. D Appl. Phys.* 42, 055009 (2009).
- 6) B. Ling, J. L. Zhao, X. W. Sun, S. T. Tan, A. K. K. Kyaw, Y. Divayana, and Z. L. Dong, "Color tunable light-emitting diodes based on p+-Si/p-CuAlO<sub>2</sub>/ n-ZnO nanorod array hetero-junctions," *Appl. Phys. Lett.* 97, 013101–013103 (2010).
- 7) H. Kawazoe, M. Yasukawa, H. Hyodo, M. Kurita, H. Yanagi, and H. Hosono, "P-type electrical conduction in transparent thin films of  $\text{CuAlO}_2$ ," *Nature* 389, 939–942 (1997).

- 8) J. T. Haraldsen, F. Ye, R. S. Fishman, J. A. Fernandez-Baca, Y. Yamaguchi, K. Kimura, and T. Kimura, "Multiferroic phase of doped delafossite  $\text{CuFeO}_2$  identified using inelastic neutron scattering," *Phys. Rev. B* 82, 020404R (2010).
- 9) H. Honso, "Recent progress in transparent oxide semiconductors: Materials and device application", *Thin Solid Films* 515, 6000-6014 (2007).
- 10) A. Kudo, H. Yanagi, H. Honso and H. Kawazoe, "SrCu<sub>2</sub>O<sub>2</sub>: A p-type conductive oxide with wide band gap", *Appl. Phys. Lett.* 73, 220 (1998).
- 11) K. Ueda, S. Inoue, S. Hirose, H. Kawazoe and H. Honso, "Transparent p-type semiconductor: LaCuOS layered oxysulfide", *Appl. Phys. Lett.* 77, 2701(2000).
- 12) H. Kawazoe, M. Yoshukawa, H. Hyodo, M. Kurita, H. Yanagi and H. Honso, "P-type electrical conduction in transparent thin films of CuAlO<sub>2</sub>", *Nature* 389, 939 (1997).
- 13) M. C. Friedel, "Sur une combinaison naturelle des oxydes de fer et de cuivre, et sur la reproduction de l'atacamite," *C. R. Hebd. Seances Acad. Sci.* 77, 211 (1873).
- 14) A. F. Rogers, "Delafossite, a cuprous metaferrite from Bisbee, Arizona," *Am. J. Sci.* 35, 290 (1913).
- 15) A. F. Rogers, "Delafossite from Kimberly, Nevada," *Am. Mineral.* 7, 102 (1922).
- 16) W. Soller and A. J. Thompson, "The crystal structure of cuprous ferrite," *Phys. Rev.* 47, 644 (1935).
- 17) T. Nozaki, K. Hayashi, and T. Kajitani, "Thermoelectric properties of delafossite-type oxide  $\text{CuFe}_{1-x}\text{Ni}_x\text{O}_2$  ( $0 \leq x \leq 0.05$ )," *J. Chem. Eng. Jpn.* 40, 1205–1209 (2007).
- 18) T. Nozaki, K. Hayashi, and T. Kajitani, "Mn-substitution effect on thermal conductivity of delafossite-type oxide  $\text{CuFeO}_2$ ," *J. Electron. Mater.* 39, 1798 (2010).

- 19) K. Hayashi, R. Fakatsu, T. Nozaki, Y. Miyazaki, and T. Kajitani, "Structural, magnetic, and ferroelectric properties of  $\text{CuFe}_{1-x}\text{Mn}_x\text{O}_2$ ," *Phys. Rev. B* 87,064418 (2013).
- 20) F. A. Benko and F. P. Koffyberg, "Opto-electronic properties of p- and n-typedelafossite,  $\text{CuFeO}_2$ ," *J. Phys. Chem. Solids* 48, 431–434 (1987).
- 21) K. Singh, A. Maignan, C. Simon, V. Hardy, E. Pachoud, and C. Martin, "The spin glass delafossite  $\text{CuFe}_{0.5}\text{V}_{0.5}\text{O}_2$ : A dipolar glass?" *J. Phys. Condens. Matter* 23, 126005 (2011).
- 22) K. El Ataoui, J.-P. Doumerc, A. Ammar, J.-C. Grenier, L. Fournès, A. Wattiaux, and M. Pouchard, "Delafossite oxides containing vanadium(III): Preparation and magnetic properties," *Solid State Sci.* 7, 710–717 (2005).
- 23) L. Shi, Z. Xia, M. Wei, J. Huang, B. Chen, Z. Long, C. Shang, Z. Ouyang, and N. Xia, "The enhanced spontaneous dielectric polarization in Ga doped  $\text{CuFeO}_2$ ," *J. Appl. Phys.* 116, 173907 (2014).
- 24) T. Elkhouni, M. Amami, C. V. Colin, and A. Ben Salah, "Structural and magnetoelectric interactions of (Ca, Mg)-doped polycrystalline multiferroic  $\text{CuFeO}_2$ ," *Mater. Res. Bull.* 53, 151–157 (2014).
- 25) S. Seki, Y. Yamasaki, Y. Shiomi, S. Igschi, Y. Onose, and Y. Tokura, "Impurity-doping-induced ferroelectricity in the frustrated antiferromagnet  $\text{CuFeO}_2$ ," *Phys. Rev. B* 75, 100403 (2007).
- 26) P. Dordor, J. P. Chaminade, A. Wichainchai, E. Marquestaut, J. P. Doumerc, M. Pouchard, and P. Hagenmuller, "Crystal growth and electrical properties of  $\text{CuFeO}_2$  single crystals," *J. Solid State Chem.* 75, 105–112 (1988).

- 27) T. Okuda, N. Jufuku, S. Hidaka, and N. Terada, “Magnetic, transport, and thermoelectric properties of the delafossite oxides  $\text{CuCr}_{1-x}\text{Mg}_x\text{O}_2$  ( $0 \leq x \leq 0.04$ )”, *Phys. Rev. B* 72, 144403 (2005).
- 28) Nagarajan, N. Duan, M.K. Jayaraj, J. Li, K.A. Vanaja, A. Yokochi, A. Draeseke, J. Tate, and A.W. Sleight, “p-Type conductivity in the delafossite structure”, *Int. J. Inorg. Mater.*, 3,265 (2001).
- 29) R. N. Attili, M. Uhrmacher, K. P. Lieb, L. Ziegeler, M. Mekata, and E. Schwarzmann, “Electric-field gradients at  $^{111}\text{Cd}$  in delafossite oxides  $\text{ABO}_2$  ( $A=\text{Ag, Cu}$ ;  $B=\text{Al, Cr, Fe, In, Nd, Y}$ )”, *Phys. Rev. B*, 53, 600 (1996).
- 30) S. Seki, Y. Onose, and Y. Tokura, “Spin-Driven Ferroelectricity in Triangular Lattice Antiferromagnets  $\text{ACrO}_2$  ( $A = \text{Cu, Ag, Li, or Na}$ )”, *Phys. Rev. Lett.* 101, 067204 (2008).
- 31) S.Y. Zheng, G.S. Jiang, J.R. Su, and C.F. Zhu, “The structural and electrical property of  $\text{CuCr}_{1-x}\text{Ni}_x\text{O}_2$  delafossite compounds”, *Mater. Lett.* 60, 3871e3873 (2006).
- 32) M. Amami, C. Colin, P. Strobel, and A.B. Salah, “Al-doping effect on the structural and physical properties of delafossite-type oxide  $\text{CuCrO}_2$ ”, *Phys. B Condens. Matter* 406, 2182e2185 (2011).
- 33) Taieb Elkhouni, Mongi Amami, Pierre Strobel, and Abdel Hamid Ben Salah, “Structural and magnetic properties of substituted delafossite-type oxides  $\text{CuCr}_{1-x}\text{Sc}_x\text{O}_2$ ”, *World J. Condens. Matter Phys.* 3, 1e8 (2013).
- 34) M. Amami, F. Jlaiel, P. Strobel, A.B. Salah, “Synthesis, structural and magnetic studies of the  $\text{CuCr}_{1-x}\text{Rh}_x\text{O}_2$  delafossite solid solution with  $0 \leq x \leq 0.2$ ”, *Mater. Res. Bull.* 46, 1729e1733 (2011).

- 35) Kiran Singh, Bohdan Kundys, Maria Poienar, and Charles Simon, “Effect of coupled ferroelectric and antiferromagnetic fluctuations on dielectric anomalies in spin induced multiferroics”, *J. Phys.: Condens. Matter* 22, 445901 (2010).
- 36) Maria Poienar, Vincent Hardy, Bohdan Kundys, Kiran Singh, Antoine Maignan, Franc-oise Damay, and Christine Martin, “Revisiting the properties of delafossite  $\text{CuCrO}_2$ : A single crystal study”, *Journal of Solid State Chemistry* 185, 56–61 (2012).
- 37) Qing-Yuan Tang , Yan-Mei Kan, Yao-Gang Li, Guo-Jun Zhang , and Pei-Ling Wang, “Effect of vanadium doping on fabrication and property of  $\text{Bi}_4\text{Ti}_3\text{O}_{12}$  ceramics”, *Scripta Materialia* 54, 2075–2080 (2006).
- 38) Dale e. Wittmer, and Relva c. Buchanan, “Low-Temperature Densification of Lead Zirconate-Titanate with Vanadium Pentoxide Additive”, *Journal of American Ceramic Society*, 64, 485-490 (1981).
- 39) Juan Rodriguez-Carvajal, FULLPROF Version 1.00, LLB, Feb 2007 (unpublished).

### List of Publications:

1. “ Structure, microstructure and dielectric studies of PVA/Sr( $\text{Co}_{1/3}\text{Nb}_{2/3}$ ) $\text{O}_3$  polymer composites” by **Nishant Barot**, Bhagwati Bishnoi, Sagufta Jahan, Prashant K. Mehta and N. L. Singh, *Invertis Journal of Science and Technology*, Vol. 10, No. 2, pp. 64-72 (2017).
2. “Structure, I-V Characteristics and Optical studies of Delafossite  $\text{CuFeO}_2$  and  $\text{CuFe}_{0.96}\text{Ti}_{0.03}\text{V}_{0.01}\text{O}_2$  Prepared Under High Vacuum” by **Nishant Barot**, Prashant K. Mehta, Devang D. Shah and C. J. Panchal, *AIP Conf. Proc.* 1837, 040031-1–040031-4 (2017).

3. "Effects of iso- and polyvalent substitutions on the short/long-range crystalline order in  $\text{CuCrO}_2$  compounds" **Nishant Barot**, Prashant K. Mehta, Ashok Rao, Riya Thomas, and Yung-Kang Kuo, Journal of Alloys and Compounds, 701, 134-143 (2019).
4. "Role of charge doping and distortions on the structural, electrical, and magnetic properties of modified  $\text{CuFeO}_2$  compounds" **Nishant Barot**, Prashant K. Mehta, Ashok Rao, Riya Thomas, Yung-Kang Kuo, and S. K. Mishra, Journal of Applied physics, J. Appl. Phys. 127, 175704 (2020).



Barot Nishant Jayeshkumar  
Research Scholar

Date: 8/7/2021  
Place: Vadodara



Dr. Prashant K. Mehta  
Research Guide  
Professor  
Department of Physics  
Faculty of Science  
The M. S. University of Baroda  
Vadodara – 390 002 (Gujarat-India)

Date: 8/7/2021  
Place: Vadodara